

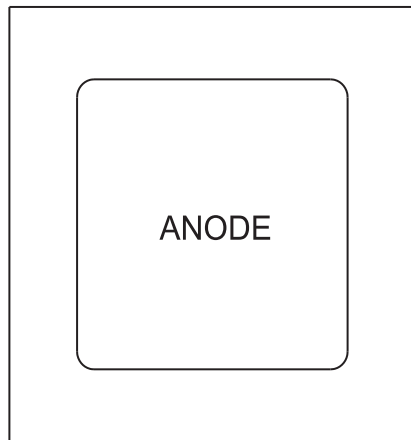
PROCESS CPZ19
Zener Diode
0.5 Watt Zener Diode Chip



PROCESS DETAILS

Process	EPITAXIAL PLANAR
Die Size	17.7 x 17.7 MILS
Die Thickness	7.5 MILS
Anode Bonding Pad Area	11 x 11 MILS
Top Side Metalization	Al - 13,000Å
Back Side Metalization	Au - 14,000Å

GEOMETRY



BACKSIDE CATHODE R0

GROSS DIE PER 4 INCH WAFER

36,642

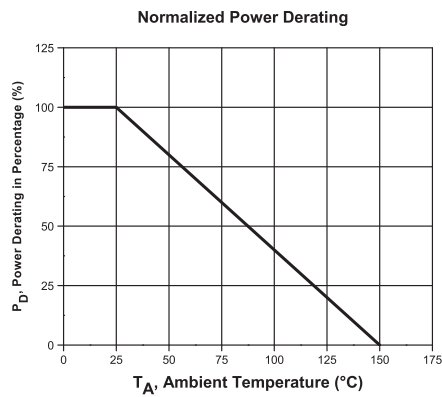
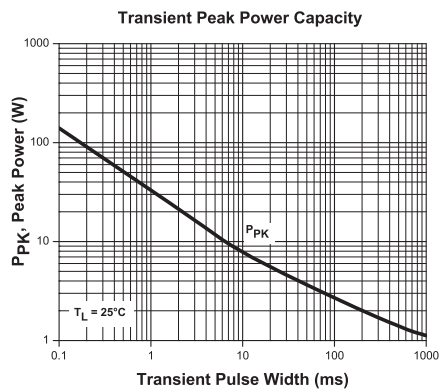
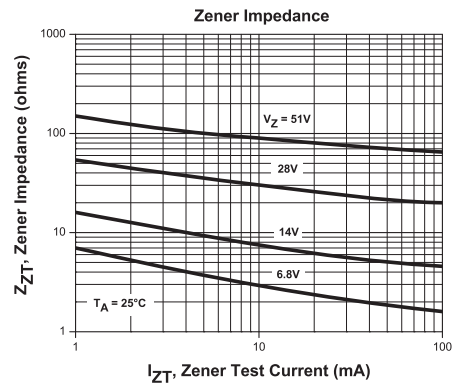
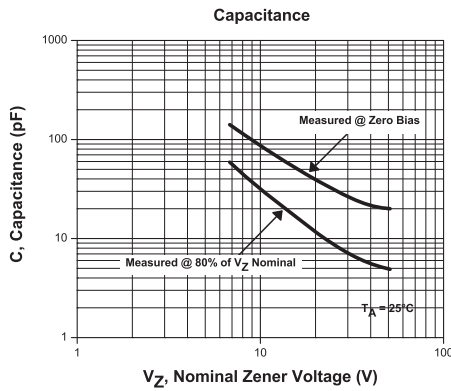
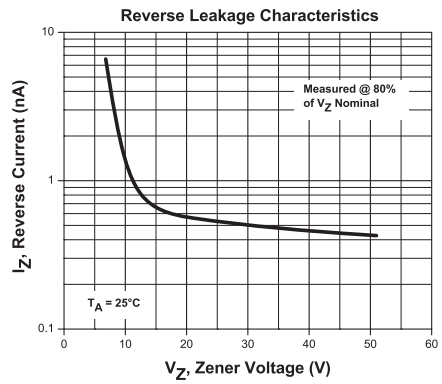
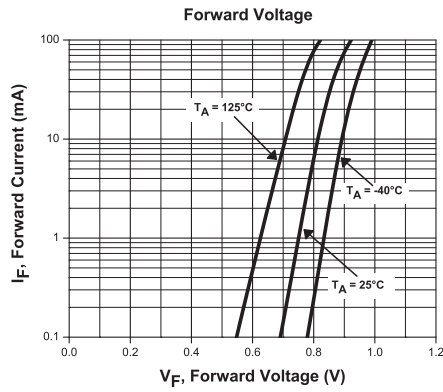
PRINCIPAL DEVICE TYPES

CMPZ5235B
THRU
CMPZ5261B

R6 (22-February 2012)

PROCESS CPZ19

Typical Electrical Characteristics



R6 (22-February 2012)